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## Features

- Wideband support up to 60 GHz
- Low insertion loss
- 1.3 dB @ 26.5 GHz
- 1.7 dB @ 45 GHz
- 1.9 dB @ 50 GHz
- 2.7 dB @ 60 GHz
- Fast switching time of 8 ns
- High port to port isolation
- 41 dB @ 26.5 GHz
- 38 dB @ 45 GHz
- 37 dB @ 50 GHz
- 36 dB @ 60 GHz
- High linearity: IIP3 of 48 dBm
- Flip-chip die, pin-to-pin compatible to the PE42524 and the PE426525


## Applications

- Test and measurement
- Microwave backhaul
- Radar
- Military communications

Figure 1•PE42525 Functional Diagram


Peregrine's HaRP technology enhancements deliver high linearity and excellent harmonics performance. It is an innovative feature of the UltraCMOS process, offering the performance of GaAs with the economy and integration of conventional CMOS.

## Absolute Maximum Ratings

Exceeding absolute maximum ratings listed in Table 1 may cause permanent damage. Operation should be restricted to the limits in Table 2. Operation between operating range maximum and absolute maximum for extended periods may reduce reliability.

## ESD Precautions

When handling this UltraCMOS device, observe the same precautions as with any other ESD-sensitive devices. Although this device contains circuitry to protect it from damage due to ESD, precautions should be taken to avoid exceeding the rating specified in Table 1.

## Latch-up Immunity

Unlike conventional CMOS devices, UltraCMOS devices are immune to latch-up.
Table 1•Absolute Maximum Ratings for PE42525

| Parameter/Condition | Min | Max | Unit |
| :--- | :---: | :---: | :---: |
| Control voltage (V1, V2) | -3.6 | 3.6 | V |
| RF input power (RFC-RFX, 50 2) |  | Fig. 2 | dBm |
| Maximum junction temperature | -65 | +150 | ${ }^{\circ} \mathrm{C}$ |
| Storage temperature range |  | ${ }^{\circ} \mathrm{C}$ |  |
| ESD voltage $\mathrm{HBM}^{*}{ }^{*}$ <br> All pins <br> RF pins to GND | 600 | V |  |

Note: * Human body model (MIL-STD 883 Method 3015).

## Recommended Operating Conditions

Table 2 lists the recommended operating conditions for PE42525. Devices should not be operated outside the recommended operating conditions listed below.

Table 2•Recommended Operating Condition for PE42525

| Parameter | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: |
| Control high (V1, V2) | 2.7 | 3.0 | 3.3 | V |
| Control low (V1, V2) | -3.3 | -3.0 | -2.7 | V |
| Control current |  | 390 |  | nA |
| RF input power, CW (RFC-RFX) ${ }^{(1)}$ |  |  | Fig. 2 | dBm |
| RF input power, pulsed (RFC-RFX) ${ }^{(2)}$ |  |  | Fig. 2 | dBm |
| Operating temperature range | -40 | +25 | +105 | ${ }^{\circ} \mathrm{C}$ |
| Notes: <br> 1) $100 \%$ duty cycle, all bands, $50 \Omega$. <br> 2) Pulsed, $5 \%$ duty cycle of $4620 \mu s$ period, $50 \Omega$. |  |  |  |  |

## Electrical Specifications

Table 3 provides the PE42525 key electrical specifications $@+25^{\circ} \mathrm{C}, \mathrm{V} 1=+3.0 \mathrm{~V}, \mathrm{~V} 2=-3.0 \mathrm{~V}$ or $\mathrm{V} 1=-3.0 \mathrm{~V}$, $\mathrm{V} 2=+3.0 \mathrm{~V}\left(\mathrm{Z}_{\mathrm{S}}=\mathrm{Z}_{\mathrm{L}}=50 \Omega\right)$, unless otherwise specified.

Table 3•PE42525 Electrical Specifications

| Parameter | Path | Condition | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Operation frequency |  |  | 9 kHz |  | 60 GHz | As shown |
| Insertion loss | RFC-RFX | $\begin{aligned} & 100 \mathrm{MHz} \\ & 100 \mathrm{MHz}-26.5 \mathrm{GHz} \\ & 26.5-45 \mathrm{GHz} \\ & 45-50 \mathrm{GHz} \\ & 50-60 \mathrm{GHz} \end{aligned}$ |  | $\begin{aligned} & 0.9 \\ & 1.3 \\ & 1.7 \\ & 1.9 \\ & 2.7 \end{aligned}$ | $\begin{aligned} & 1.1 \\ & 1.6 \\ & 2.0 \\ & 2.3 \\ & 3.8 \end{aligned}$ | dB <br> dB <br> dB <br> dB <br> dB |
| Isolation | All paths | $\begin{aligned} & 100 \mathrm{MHz} \\ & 100 \mathrm{MHz}-26.5 \mathrm{GHz} \\ & 26.5-45 \mathrm{GHz} \\ & 45-50 \mathrm{GHz} \\ & 50-60 \mathrm{GHz} \end{aligned}$ | $\begin{aligned} & 74 \\ & 38 \\ & 33 \\ & 32 \\ & 29 \end{aligned}$ | $\begin{aligned} & 80 \\ & 41 \\ & 38 \\ & 37 \\ & 36 \end{aligned}$ |  | dB <br> dB <br> dB <br> dB <br> dB |
| Return loss (active port) | RFC-RFX | $\begin{aligned} & 100 \mathrm{MHz} \\ & 100 \mathrm{MHz}-26.5 \mathrm{GHz} \\ & 26.5-45 \mathrm{GHz} \\ & 45-50 \mathrm{GHz} \\ & 50-60 \mathrm{GHz} \end{aligned}$ |  | $\begin{aligned} & 21 \\ & 17 \\ & 18 \\ & 15 \\ & 13 \end{aligned}$ |  | dB <br> dB <br> dB <br> dB <br> dB |

Table 3•PE42525 Electrical Specifications (Cont.)

| Parameter | Path | Condition | Min | Tур | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Return loss (RFC port) | RFC-RFX | $\begin{aligned} & 100 \mathrm{MHz} \\ & 100 \mathrm{MHz}-26.5 \mathrm{GHz} \\ & 26.5-45 \mathrm{GHz} \\ & 45-50 \mathrm{GHz} \\ & 50-60 \mathrm{GHz} \end{aligned}$ |  | $\begin{aligned} & 21 \\ & 20 \\ & 18 \\ & 16 \\ & 14 \end{aligned}$ |  | dB <br> dB <br> dB <br> dB <br> dB |
| 2nd harmonic, 2fo | RFC-RFX | +25 dBm output power, 1 GHz <br> +25 dBm output power, 2 GHz <br> +25 dBm output power, 6.5 GHz <br> +25 dBm output power, 13.4 GHz |  | $\begin{aligned} & 73 \\ & 77 \\ & 89 \\ & 92 \end{aligned}$ |  | dBc <br> dBc <br> dBc <br> dBc |
| Input 1dB compression point ${ }^{(1)}$ |  |  |  | Fig. 2 |  | dBm |
| Input IP2 |  | $\begin{aligned} & 1 \mathrm{GHz} \\ & 2 \mathrm{GHz} \\ & 6.5 \mathrm{GHz} \\ & 13.4 \mathrm{GHz} \end{aligned}$ |  | $\begin{gathered} 93 \\ 98 \\ 109 \\ 112 \end{gathered}$ |  | dBm <br> dBm <br> dBm <br> dBm |
| Input IP3 |  | $\begin{array}{\|l\|} \hline 1 \mathrm{GHz} \\ 2 \mathrm{GHz} \\ 6 \mathrm{GHz} \\ 13.4 \mathrm{GHz} \end{array}$ |  | $\begin{aligned} & 49 \\ & 48 \\ & 46 \\ & 46 \end{aligned}$ |  | dBm <br> dBm <br> dBm <br> dBm |
| Video feed through ${ }^{(2)}$ |  | DC measurement |  | 30 |  | $m V_{P P}$ |
| RF $\mathrm{T}_{\text {RISE }} / \mathrm{T}_{\text {FALL }}$ |  | 10\%/90\% RF |  | 3 |  | ns |
| Settling time |  | $50 \%$ CTRL to 0.05 dB final value |  | 48 | 60 | ns |
| Switching time |  | $50 \%$ CTRL to $90 \%$ or $10 \%$ RF |  | 8 | 12 | ns |

Notes:

1) The input 1 dB compression point is a linearity figure of merit. Refer to Table 2 for the RF input power (50 2 ).
2) Measured with a 3.5 ns rise time, $-3.0 /+3.0 \mathrm{~V}$ pulse and 100 MHz bandwidth.

## Control Logic

Table 4 provides the control logic truth table for the PE42525. States 2 and 3 are used in normal switching operations.

Table 4•Truth Table for PE42525

| V 1 | V 2 | RF1 | RF2 | State |
| :---: | :---: | :---: | :---: | :---: |
| -3.0 V | -3.0 V | OFF | OFF | 1 |
| -3.0 V | +3.0 V | OFF | ON | 2 |
| +3.0 V | -3.0 V | ON | OFF | 3 |
| +3.0 V | +3.0 V | ON | ON | 4 |

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Figure 2•Power De-rating Curve, $9 \mathrm{kHz}-60 \mathrm{GHz},-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ Ambient, $50 \Omega$


## Typical Performance Data

Figure 3-Figure 12 show the typical performance data at $25^{\circ} \mathrm{C}, \mathrm{V} 1=+3.0 \mathrm{~V}, \mathrm{~V} 2=-3.0 \mathrm{~V}$ or $\mathrm{V} 1=-3.0 \mathrm{~V}, \mathrm{~V} 2=$ $+3.0 \mathrm{~V}\left(Z_{S}=Z_{L}=50 \Omega\right)$, unless otherwise specified.

Figure $3 \cdot$ Insertion Loss vs Temperature (RFC-RFX)


Figure 4•RFC Port Return Loss vs Temperature


Figure 5 • Active Port Return Loss vs Temperature


Figure 6•Insertion Loss vs V1/V2 (RFC-RFX)


Figure 7•RFC Port Return Loss vs V1/V2


Figure 8 • Active Port Return Loss vs V1/V2


Figure 9 • Isolation vs Temperature (RFX-RFX)


Figure 10 • Isolation vs Temperature (RFC-RFX)


Figure 11•Isolation vs V1/V2 (RFX-RFX)


Figure $12 \cdot$ Isolation vs V1/V2 (RFC-RFX)


## Evaluation Setup

The PE42525 s-parameter data and input 1dB compression point up to 60 GHz (Table 3 and Figure 3-
Figure 12) were taken using either co-planar waveguide with ground (CPWG) or grounded co-planar waveguide (GCPW) on an alumina substrate and RF probes.

The PE42525 2nd harmonic, input 1dB compression point below 18 GHz , input IP3 measurements, settling time and switching time (Table 3) were taken on a PCB using 2.92 mm connectors.
Bypass capacitors are not required.
Figure 13 • Alumina Substrate Board for PE42525


## Pin Configuration

This section provides pin information for the PE42525. Figure 14 shows the pin configuration of this device. Table 5 provides a description for each pin.

Figure 14• Pin Configuration (Bumps Up) for PE42525


## Die Mechanical Specifications

This section provides the die mechanical specifications for the PE42525.
Table 6-Mechanical Specifications for PE42525

| Parameter | Min | Typ | Max | Unit |  |
| :--- | :---: | :---: | :---: | :---: | :---: |
| Die size, singulated (x, y) | $2485 \times 2139$ | $2495 \times 2149$ | $2505 \times 2159$ | $\mu \mathrm{~m}$ | Including excess silicon, <br> maximum tolerance $= \pm 10$$\mu \mathrm{~m}$ |,

Table 7 • Pin Coordinates for PE42525 ${ }^{*}$ *)

| Pin \# | Pin Name | Pin Center ( $\mu \mathrm{m}$ ) |  |
| :---: | :---: | :---: | :---: |
|  |  | X | Y |
| 1 | GND | 1128.5 | -958.5 |
| 2 | GND | 731.5 | -646.5 |
| 3 | V1 | 253.5 | -958.5 |
| 4 | V2 | -253.5 | -958.5 |
| 5 | GND | -1128.5 | -958.5 |
| 6 | GND | -731.5 | -646.5 |
| 7 | RF1 | -785.5 | -121.5 |
| 8 | GND | -931.5 | 363.5 |
| 9 | GND | -1091.5 | 913.5 |
| 10 | GND | -503.5 | 753.5 |
| 11 | RFC | 0 | 629 |
| 12 | GND | 503.5 | 753.5 |
| 13 | GND | 1091.5 | 913.5 |
| 14 | GND | 931.5 | 363.5 |
| 15 | RF2 | 785.5 | -121.5 |
| 16 | GND | 253.5 | 183.5 |
| 17 | GND | 253.5 | -326.5 |
| 18 | GND | -253.5 | 183.5 |
| 19 | GND | -253.5 | -326.5 |
| Note: * All pin locations originate from the die center and refer to the center of the pin. |  |  |  |

Figure 15 • Pin Layout for PE42525 ${ }^{(1)(2)}$


## Notes:

1) Drawings are not drawn to scale.
2) Singulated die size shown, bump side up.

## Tape and Reel Specification

This section provides the tape and reel specifications for the PE42525.
Figure 16•Tape and Reel Specifications for PE42525


| Pocket | Nominal | Tolerance |
| :---: | :---: | :---: |
| Ao | 2.41 | $\pm 0.05$ |
| Bo | 2.76 | $\pm 0.05$ |
| Ko | 0.39 | $\pm 0.05$ |

Notes:
Not Drawn to Scale
Dimensions are in millimeters
Maximum cavity angle 5 degrees
Bumped die are oriented active side down


Device Orientation in Tape

## Ordering Information

Table 8 lists the available ordering code for the PE42525 as well as shipping method.

## Table 8•Order Code for PE42525

| Order Code | Description | Packaging | Shipping Method |
| :---: | :---: | :---: | :---: |
| PE42525A-X | PE42525 SPDT RF switch | Die on tape and reel | 500 die/T\&R |

## Document Categories

## Advance Information

The product is in a formative or design stage. The datasheet contains design target specifications for product development. Specifications and features may change in any manner without notice.

## Preliminary Specification

The datasheet contains preliminary data. Additional data may be added at a later date. Peregrine reserves the right to change specifications at any time without notice in order to supply the best possible product.

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